MRFIC1505 Rev. 1, 08/2004

MRFIC1505/MRFIC1505A Integrated GPS Downconverter

1.575 GHz GPS DOWNCONVERTER

This integrated circuit is intended for GPS receiver applications. The dual conversion design is implemented in Motorola's low–cost, high–performance MOSAIC 5. silicon bipolar process and is packaged in a low–cost surface mount LQFP–48 package. In addition to the mixers, a VCO, PLL, Crystal Oscillator, A/D converter and a loop filter are integrated on–chip. Output IF is nominally 4.1 MHz.

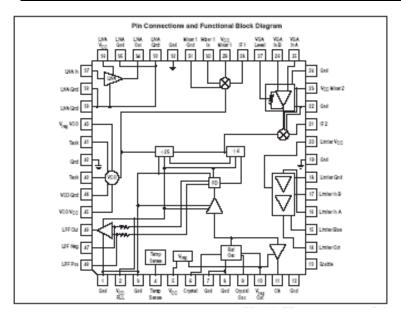
- 105 dB Typical Conversion Gain
- 2.7 V Operation
- 28 mA Typical Current Consumption
- Low-Cost, Low-Profile Plastic LQFP Package

MOSAIC 5 is a trademark of Motorola, Inc.

Ordering Information

Device	Operating Temperature Range	Package
MRFIC1505R2	$T_A = -40 \text{ to } 85^{\circ}\text{C}$	LQFP-48
MRFIC1505AR2	$T_A = -40 \text{ to } 85^{\circ}\text{C}$	LQFP-48









Maximum Ratings

Rating	Symbol	Value	Unit
DC Supply Voltage	V _{DD}	5.0	Vdc
DC Supply Current	I _{DD}	60	mA
Operating Ambient Temperature	T _A	-40 to 85	°C
Storage Temperature Range	T _{stg}	-65 to 150	°C
Lead Soldering Temperature Range	-	260	°C

Note: Maximum Ratings are those values beyond which damage to the device may occur. Functional operation should be restricted to the limits in the Electrical Characteristics tables.

Electrical Characteristics (VCC = 2.7 to 3.3 V; TA = -40 to 85°C; Enable = 2.7 V unless otherwise noted)

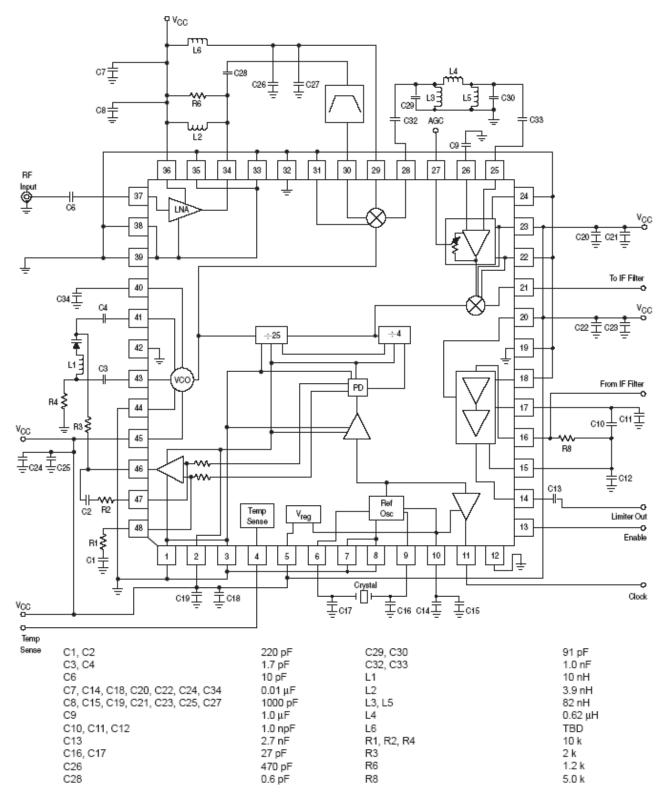
Total Device VCC 2.7 3.0 3.3 V	Characteristic	Symbol	Min	Тур	Max	Unit
Supply Current (TA = 25°C, VCC = 2.7 V, Enable = 2.7V)	Total Device	<u> </u>				1
Supply Current (TA = 25°C, VCC = 2.7 V, Enable = 2.7V)	Supply Voltage	V _{CC}	2.7	3.0	3.3	V
(TA = 28°C, VCC = 2.7 V, Enable = 2.7V) Property CC Property Property	Supply Current	i		00	00	^
CC	(TA = 25°C, VCC = 2.7 V, Enable = 2.7V)	Icc	_	28	36	mA
R Amplifier RF Input Frequency	1 11 /	1		2.0	4.0	mΔ
RF Input Frequency	$(TA = 25^{\circ}C, VCC = 2.7 \text{ V}, Enable = 2.7 \text{ V})$	'CC	_	2.0	4.0	ША
Input Impedance	•					
Input VSWR	· · · ·		-	1575.42	-	MHz
Gain Nise Figure NF	· · ·	Z _{in}	-	50	-	Ω
Noise Figure	Input VSWR	VSWR _{in}	-	2.0	-	_
1.0 dB Compression (Measured at Output)	Gain	G	13	15	_	dB
Input Frequency	Noise Figure	NF	_	2.0	_	dB
Input Frequency	1.0 dB Compression (Measured at Output)	P _{1dB}	_	1.0	_	dBm
Gain Gain Gain 14 - dB Noise Figure NF - 13 - dB 1.0 dB compression (Measured at Output) P1dB - -13 - dB MF First Local Oscillator Frequency f1O1 - 1636.8 - MHz MH	First Mixer	•		-		•
Noise Figure	Input Frequency	f _{in}	_	1575.42	_	MHz
1.0 dB compression (Measured at Output)	Gain	G	10	14	_	dB
First Local Oscillator Frequency	Noise Figure	NF	-	13	_	dB
First Intermediate Frequenc	1.0 dB compression (Measured at Output)	P _{1dB}	-	-13	-	dBm
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	First Local Oscillator Frequency	f _{LO1}	-	1636.8	_	MHz
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	First Intermediate Frequenc	f _{IF1}	-	61.38	_	MHz
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	LO Leakage at IF Port	-	=	-40	_	dBm
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	LO Leakage at RF Port	-	-	-50	_	dBm
$ \begin{array}{ l c c c c c } & f_{in} & - & 61.38 & - & MHz \\ \hline lnput Impedance & Z_{in} & - & 230 & - & \Omega \\ \hline Output Impedance & Z_{out} & - & 50 & - & \Omega \\ \hline Second Local Oscillator Frequency & f_{LO2} & - & 65.47 & - & MHz \\ \hline Second Intermediate Frequency & f_{IF2} & - & 4.092 & - & MHz \\ \hline LO Leakage at IF Port & - & - & -40 & - & dBm \\ \hline Gain & G & 40 & 43 & - & dB \\ \hline Cascaded Noise Figure & NF & - & 9.3 & - & dB \\ \hline 1.0 dB Compression Point (Measured at Output) & P_{1dB} & - & -13 & - & dBm \\ \hline Limiting Amplifier & & & & & & & & \\ \hline Second Intermediate Frequency & f_{IF2} & - & 4.092 & - & MHz \\ \hline Input Signal Level & - & 4.0 & 11 & 31 & Mv \\ \hline Output Voltage Swing (into 10 pf II100 k\Omega & V_{out} & 800 & - & - & mVpp \\ \hline DC Output Level & - & - & 1.4 & - & V \\ \hline Gain & G & - & 50 & - & dB \\ \hline Reference Oscillator & & & & & & & \\ \hline Reference Frequency & f_r & - & 16.368 & - & MHz \\ \hline Reference Frequency & f_r & - & 16.368 & - & MHz \\ \hline \end{array}$	Output Impedance	Z _{out}	-	50	_	Ω
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	First IF Amplifier and Second Mixer					•
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	Input Frequency	f _{in}	_	61.38	-	MHz
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	Input Impedance	Z _{in}	-	230	_	Ω
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	Output Impedance	Z _{out}	_	50	-	Ω
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	Second Local Oscillator Frequency	f _{LO2}	-	65.47	_	MHz
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	Second Intermediate Frequency		-	4.092	_	MHz
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	LO Leakage at IF Port		_	-40	-	dBm
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	Gain	G	40	43	-	dB
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	Cascaded Noise Figure	NF	-	9.3	_	dB
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	1.0 dB Compression Point (Measured at Output)	P _{1dB}	_	-13	-	dBm
	Limiting Amplifier					
	Second Intermediate Frequency	f _{IF2}	_	4.092	_	MHz
DC Output Level - - 1.4 - V Gain G - 50 - dB Reference Oscillator Reference Frequency f _r - 16.368 - MHz	Input Signal Level		4.0	11	31	Mv
DC Output Level - - 1.4 - V Gain G - 50 - dB Reference Oscillator Reference Frequency f _r - 16.368 - MHz	Output Voltage Swing (into 10 pf ll100 k Ω	V _{out}	800	_	_	mVpp
Reference Oscillator Reference Frequency	DC Output Level		_	1.4	_	V
Reference Frequency f _r - 16.368 - MHz	Gain	G	_	50	_	dB
	Reference Oscillator	L		11		
	Reference Frequency	f _r	_	16.368	_	MHz
	Reference Frequency Input Level (Crystal Output Pin)	_	_	500	_	mVpp



Electrical Characteristics (VCC = 2.7 to 3.3 V; TA = -40 to 85° C; Enable = 2.7 V unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
Reference Oscillator Output Voltage Level (Into 15 pf II 10 kΩ)	_	750	-	-	mVpp
Reference Clock Input Drive Level	_	400	800	1500	mVpp
PLL					
First Local Oscillator Frequency	f _{LO1}	_	1636.8	_	MHz
Second Local Oscillator Frequency	f _{LO2}	_	65.47	-	MHz
VCO C/N (at 10 kHz Offset)	_	_	-80	-	dBc/Hz
VCO Gain (TBD Varactor)	_	_	200	-	MHz/V
Enable					
Enable Active Level	_	0.8 x V _{CC}	V _{CC}	-	V
Disable Active Level	_	_	0	0.2 x V _{CC}	V
Voltage Regulator					
Regulator Output Voltage	Vo	2.1	2.3	2.5	V
$(V_{CC} = 2.7 \text{ to } 3.3 \text{ V}, I_{out} = 3.0 \text{ mA})$	VO	2.1	2.5	2.5	V
MRFIC505 Temperature Sense Specs					
Temperature Sensor Output Voltage @ 25°C	_	1.2	1.28	1.375	V
Temperature Sensor Slope over Temperature	_	_	5.0	-	mV/°C
MRFIC505A Temperature Sense Specs	•				
Temperature Sensor Output Voltage @ 25°C	_	1.270	1.395	1.463	V
Temperature Sensor Slope over Temperature	_	_	5.0	-	mV/°C





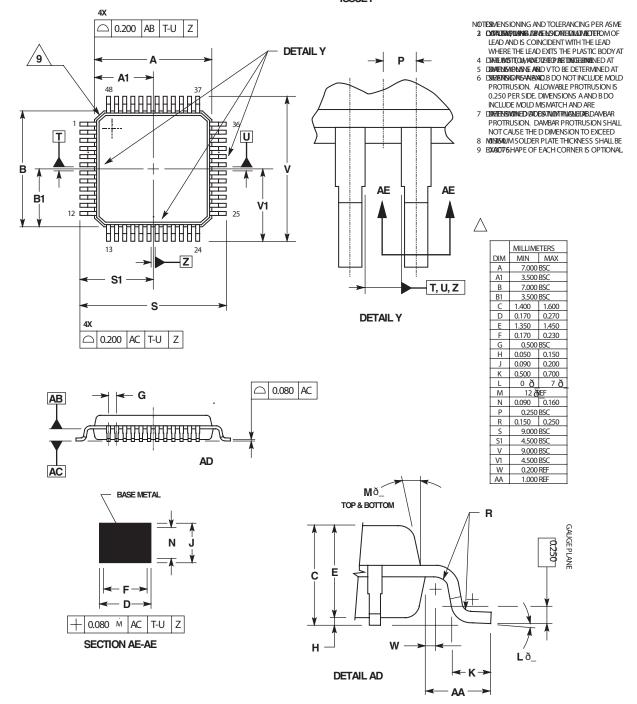
NOTES: 1. R8 must be set to match your 2nd IF filter impedance.
2. Layout of capacitors C10, C11, C12 is critical for stability of Limiter.

Figure 1 Applications Schematic (1636.8 MHz LO)



Outline Dimensions

PLASTIC PACKAGE CASE 932-03 (LQFP-48) ISSUE F





NOTES



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MRFIC1505 Rev. 1 08/2004